

# MEMORY IC

PartNo.	ProductNo.	Manuf.	Description	words/bits	Access time(nS)	Program Volt	Volt.(Vcc)	Size(bits)	Pins/Package
19375	MB8516	FUJITSU							DIP
22743	MX27C1000QC-15	MXIC	CMOS EPROM	128K*8	150nS	12.5V	5V	1M	32P/PLCC
22744	MX27C256QC-15	MXIC	CMOS EPROM	32K*8	150nS	12.5V	5V	256K	32P/PLCC
1458	MX27C4100MC-12	MXIC	CMOS EPROM	512K*8	120ns	12.5Vpp	5V	4M	40P/SOP
22745	MX27C512PC-55	MXIC	CMOS EPROM	64K*8	120nS	12.5V	5V	512K	28P/DIP
22747	MX27C512QC-55	MXIC	CMOS EPROM	64K*8	55nS	12.5V	5V	512K	32P/PLCC
22748	MX27C512QC-90	MXIC	CMOS EPROM	64K*8	90nS	12.5V	5V	512K	32P/PLCC
22749	MX27C8000QC-12	MXIC	CMOS EPROM	1M*8	120nS	12.5V	5V	8M	32P/PLCC
22750	MX27L2000PC-15	MXIC	CMOS EPROM	256K*8	150nS	12.5V	2.7~3.6V	2M	32P/DIP
23226	NM27C256Q150	N.S	可重複燒錄EPROM	32K*8	150nS	12.75Vpp	5V	256K	DIP
1465	NM27C256Q90	Fairchild	High Performance CMOS EPROM	32K*8	90nS	12.75Vpp	5V	256K	28P/DIP
23599	NM27C256V150	N.S	High Performance CMOS EPROM	32K*8	150ns		5V ±0%	256K	32P/PLCC
18672	NM27C256V200	N.S	High Performance CMOS EPROM	32K*8	200ns	12.75Vpp	5V	262,144	32P/PLCC
1467	NM27C512Q150	N.S	EPROM 64K*8 DIP	64K*8	150ns	12.75Vpp	5V	512K	28P/DIP
18673	P27C220-150V05	INTEL	2M-BIT [256Kx8/128x16] CMOS EPROM	256K*8 or 128*16	150ns	12.5Vpp	5V	2M	40P/DIP
18674	TMS27C020-12JE	T.I.	Programmable Read-only Memories	256K*8	120ns	12.75Vpp	5V	2M	32P/DIP
1475	TMS27C020-12JL	T.I.	Programmable Read-only Memories	256K*8	120ns	12.75Vpp	5V	2M	32P/DIP
18675	TMS27C020-15JL	ST(SGS)	Programmable Read-only Memories	256K*8	150ns	12.75Vpp	5V	2M	32P/DIP
18676	TMS27C256-12JL	ST(SGS)	READ-ONLY MEMORY	32K*8	120ns	12.5Vpp	5V	256K	32P/DIP
3196	TMS27C512-10JL	T.I.	Programmable Read-only Memories	64K*8	100nS	12.75Vpp	5V	512K	28P/DIP
18677	TMS27PC128-1NL	ST(SGS)	READ-ONLY MEMORY	16K*8	150ns	12.5Vpp	5V	128K	28P/DIP
1484	UPD27C1024AD-15	NEC	1M-BIT [128K*8/64K*16] CMOS EPROM	64K*16	150ns	12.75Vpp	5V	1M	40P/DIP
15277	W27C257-10	WINBOND	Electrically Erasable EPROM	32K*8	100nS	12Vpp	5V	256K	28P/DIP
1433	W27C512-45	WINBOND	Electrically Erasable EPROM	64K*8	45ns	12Vpp	5V	512K	28P/DIP
18678	W27C512P-45	WINBOND	Electrically Erasable EPROM	64K*8	45ns	12Vpp	5V	512K	32P/PLCC
23150	W27C512P-70	WINBOND	ELECTRICALLY ERASABLE EPROM	64K*8	70nS		5V	512K	32P/PLCC
16558	W27E010-70	WINBOND	1MElectrically Erasable EPROM	128K*8	70nS	12Vpp	5V	128K*8	32P/DIP
15308	W27E010P-70	WINBOND	1MElectrically Erasable EPROM	128K*8	70nS	12Vpp	5V	1M	32P/PLCC
1487	W27E257-12	WINBOND	32K*8Electrically Erasable EPROM	32K*8	120ns	12Vpp	5V	256K	28P/DIP
1488	W27E512-70	WINBOND	Electrically Erasable EPROM	64K*8	70ns	12Vpp	5V	512K	28P/DIP
14204	MBM27C128-20	FUJITSU	EPROM 16K*8 DIP	16K*8	200ns		5V	128K	28P/DIP

## 燒錄一次 EPROM OTP EPROM

詳細產品規格--請點擊 [www.100y.com.tw](http://www.100y.com.tw)

PartNo.	ProductNo.	Manuf.	Description	words/bits	Access time(nS)	Program Volt	Volt.(Vcc)	Size(bits)	Pins/Package
18606	A276308L-70	AMIC	64K*8 OTP CMOS EPROM	65,536*8bit	70ns	12.75V	5V	512K	32P/PLCC
23517	AM27C010-90DC	AMD	1 Megabit CMOS EPROM		45nS		5V	128K*8Bit	32P/DIP
8508	AM27C256-120JC	AMD	256 Kilobit (32 K*8-Bit) CMOS EPROM	32K*8	120nS	12.75Vpp	5V	256K	32P/PLCC
1428	AM27C64-200PC	AMD	64 Kilobit (8K*8-Bit) CMOS EPROM	8K*8	200ns	12.75Vpp	5V	64K	28P/DIP
18643	AT27BV010-90JC	ATMEL	Unregulated Battery-Voltage OTP CMOS EPROM	128K*8	90ns	12.75V	6.25V	1Megabit	32P/PLCC
1434	AT27BV040-15TC	ATMEL	Unregulated Battery-Voltage High-Speed OTP EPROM	512K*8	150ns	14Vpp	5V	4M	32P/TSOP
1425	AT27C010-120JC	ATMEL	1Megabit (128K*8) OTP COMS EPROM	128K*8	120ns	14Vpp	5V	1M	32P/PLCC
1426	AT27C010-15JC	ATMEL	1 Megabit (128K*8) OTP CMOS EPROM	128k*8	150nS	14Vpp	5V	1M	32P/PLCC
1436	AT27C010-45PC	ATMEL	1-Megabit (128K*8) OTP EPROM	128K*8	45ns	14Vpp	5V	1M	32P/DIP
17681	AT27C020-70PC	ATMEL	2-megabit (256K*8) OTP EPROM	256K*8	70ns	14Vpp	5V	2M	32P/DIP
1427	AT27C040-70PC	ATMEL	4-Megabit (512K*8) OTPEPROM	512K*8	70ns	14Vpp	5V	4M	32P/DIP
15274	AT27C080-10JC	ATMEL	8-Megabit (1M*8) OTP EPROM	1M*8	100nS	14Vpp	5V	8M	32P/PLCC
15306	AT27C080-90PI	ATMEL	8-Megabit (1M*8) OTP EPROM	1M*8	90nS	14Vpp	5V	8M	32P/DIP
22458	AT27C2048-90JC	ATMEL	2-Megabit OTP EPROM	128*16	55nS	one-time program-mable	5V	2K	44P/PLCC
18645	AT27C256R-25JC	ATMEL	256K(32K*8) OTP EPROM	32K*8	25ns	14Vpp	5V	256K	32P/PLCC
1432	AT27C512R-12PC	ATMEL	512K(64K*8) OTP EPROM	64K*8	120ns	14Vpp	5V	512K	28P/DIP
22459	AT27C512R-15TC	ATMEL	-512K OTP EPROM	64*8	45nS	-100ms/byte	5V	512K	28P/TSOP
8511	AT27C512R-45JC	ATMEL	512K(64K*8) OTPEPROM	64K*8	45ns	14Vpp	5V	512K	32P/PLCC
18646	AT27C512R-70JC	ATMEL	512K(64K*8) OTPEPROM	64K*8	70ns	14Vpp	5V	512K	32P/PLCC
18647	AT27C512R-70PC	ATMEL	512K(64K*8) OTPEPROM	64K*8	70ns	14Vpp	5V	512K	28P/DIP
22460	AT27C512R-70TC	ATMEL	-512K OTP EPROM	64*8	45nS	-100ms/byte	5V	512K	28P/TSOP
18648	AT27C512R-90JC	ATMEL	512K(64K*8) OTPEPROM	64K*8	90ns	14Vpp	5V	512K	32P/PLCC
23533	AT27C512R-90PC	ATMEL	OTP EPROM	64K*8	45nS		-2~14V	512K	28P/DIP
18664	AT27C512R-90RC	ATMEL	512K(64K*8) OTPEPROM	64K*8	90ns	14Vpp	5V	512K	28P/SOIC
14361	AT27LV010A-12JC	ATMEL	Low Voltage OTP EPROM	128K*8	120nS	14Vpp	5V	1M	32P/PLCC
18665	FM27C256Q120	Fairchild	High Performance CMOS EPROM	32K*8	120ns	12.75Vpp	5V	262,144	28P/DIP
18667	ICE27C512-70DC	ICE	512kbit(64K*8) OTP EPROM	64K*8	70ns	5.5V	12V	512K	28P/DIP
18668	ICE27C512-70PC	ICE	512kbit (64K*8) OTP EPROM	64K*8	70ns	5.5V	12V	512K	32P/PLCC
18669	ICE27C512-70SC	ICE	512kbit (64K*8) OTP EPROM	64K*8	70ns	5.5V	12V	512K	28P/TSOP
14954	M27C256B-12F1	ST(SGS)	UVEPROM and OTP EPROM	32K*8	120ns	12.75Vpp	5V	256K	28P/DIP

